

Item	PN	Size	Value	Desc	MFG	Quantity	Reference	Type
1	CR2032	20 mm dia. x 3.2 mm	CR2032	Panasonic CR2032 3V 225mAh coin battery with leads, 20 mm dia. x 3.2 mm	Panasonic	1	BATT1	Battery
2	GRM033R71A103KA01D	201	10nF	Cap, 0201 X7R 10V 10nF 10%	Murata	1	C3	Capacitor
3	GJM0335C1E0R8WB01D	201	0p8F	Cap, 0p8F, 0201, COG, 25V, 0.05pF	Murata	1	C5	Capacitor
4	GJM0335C1E1R2WB01	201	1p2F	Cap, 1p2F, 0201, COG, 25V, 0.05pF	Murata	1	C6	Capacitor
5	GRM033R60J104KE19D	201	0.1uF	Cap, 0201 X5R 6.3V 0.1uF 10%	Murata	3	C7, C65, C66	Capacitor
6	GRM155R60J105KE19D	402	1uF	Cap, 0402 X5R 6.3V 1uF 10%	Murata	3	C31, C35, C36	Capacitor
7	GRM0335C1H9ROCA01D	201	9pF	Cap, 9pF, 0201, COG, 25V, 0.25pF	Murata	1	C87	Capacitor
10	BLM03HG601SN1D	201	BLM03HG601SN1D	FB 600 OHM@100 MHz 1.6 OHM DCR 150MA 0201	Murata	1	L7	Beads
11	LQM18PN2R2MFRL	1.6x0.8x0.75 mm	2u2H	IND, 2u2H, 0603, 750mA, DCR 0.375R, 20%, shielded, 1.6x0.8x1 mm	Murata	1	L25	Inductor
14	RR0603(0201)L1002FT	201	10K 1%	Resistor 0201 10K ohms 1%	SUPEROHM	1	R78	Resistor
18	W25X40CLUXIG	2x3x0.6 mm	W25X40CLUXIG	SPI flash, 4 Mbit, 4Kbytes sector, USON-8, 2x3x0.6 mm	Winbond	1	U67	IC
19	BSS84W-7-F	SOT-323	BSS84W7	P channel enhancement MOSFET, -1.6V Vth, 6 ohms RDS, 130mA IDmax, SOT323	DIODES	1	U71	DIODES
20	DA14580-01AT2	5x5x0.9 mm	DA14580-01AT2	Low Power BT SOC, 4mA RF active, 0dBm Tx, -93dBm sensitivity, QFN40, 5x5x1 mm	Dialog	1	U77	IC
21	7M-16.000MEEQ-T	3.2x2.5x0.8 mm	7M-16.000MEEQ-T	CRYSTAL 16 MHZ 10PF SMD 3.2x2.5x0.8 mm 80R 10ppm	TXC	1	X8	Crystal